E lectronic phase diagram s of carriers in self-assem bled InA s/G aA s quantum dots: violation of H und's rule and the A ufbau principle for holes

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We study the orbital and spin con gurations of up to six electrons or holes charged into selfassembled InA s/G aAs quantum dots via single-particle pseudopotential and many-particle con guration interaction method. We nd that while the charging of electrons follows both H und's rule and the A ufbau principle, the charging of holes follows a non-trivial charging pattern which violates both the A ufbau principle and H und's rule, and is robust against the details of the quantum dot size. The predicted hole charging sequence o ers a new interpretation of recent charging experiments.

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The remarkable combination of three-dimensional spatial con nem ent in quantum -dots with the ability to integrate them into carrier-transporting device structures enables storage and retrieval of electrons [1, 2, 3, 4, 5, 6], to the bene t of fiture quantum -computing [7, 8], m em ory [9, 10], and single-photon [11] applications. Unlike real atom s, where large C ou lom b repulsion energies J ' 10 eV lim it the num ber of ionized species to just a few, sem iconductor quantum dots can be loaded by as many as six [1] to ten [12] electrons in colloidal [12] and selfassembled [1, 2, 3] dots, and up to hundreds of electrons in electrostatically con ned dots [4, 5, 6]. Furtherm ore, one can measure for each ionization state the stable spincon guration [1, 4, 5, 6], the energy to add another electron [1, 2, 4, 5, 12] as well as the attendant spectroscopic shifts with charging [3, 13]. Like real atom s, the stable spin con quration observed in electrostatic dots [4, 5, 6], having lateral dim ensions of 500-1000 A, follow the rules of atom ic physics; that is, the s, p, d, ... shells are occupied in successive order with no holes left behind (Aufbau principle) and with maximum spin (Hund's rule). Recently, it became possible to load and measure electrons [1, 2] and holes [2, 14, 15] into much smaller 200 x 40 A), epitaxially grown self-assembled dots of InG aA s/G aA s. The analysis of the results, how ever, was based on the e ective-m ass approximation (EMA) theoretical fram ework [16], (which is designed for dots much larger than the exciton Bohr radius), leading to the conclusion that electronic con gurations are atom iclike. Electronic structure calculations for self-assembled dots [17] reveal that while for electrons the C oulom b energy J_{ee} ' 20 m eV is sm aller than the level spacing 50-70 m eV, for holes the C oulom b repulsion J_{hh} ' 15-25 m eV is comparable to the level spacing ′ 10-20 m eV . This opens the possibility of observing for holes some stable, exotic spin con gurations that defy the rules of atom ic physics. We have applied a combination of an atom istic pseudopotential description [17] for the singleparticle level structure, with a many-body con guration interaction (CI) description [18] of many-particle e ects

to both electron and hole loading into InG aA s/G aA s self-

assembled quantum -dots. We calculate the generalized electronic phase diagram of the system showing which many-particle con gurations are energetically stable for various p-p and p-d splitting of the single-particle levels. We nd that while electron bading follows both the Aufbau principle and H und's rule, hole bading gives rise to stable but unusual spin con gurations. While these calculated con gurations agree with recent measurements [14, 15], they di er from their interpretation [15], which assumes 2 dimensional (2D) parabolic models [19] that have been employed extensively and successfully to analyze large electrostatically con ned dots. [4, 5, 6]. The reason for the failure of the simpler interpretation is that parabolic models ignore the inter-band and inter-valley coupling existing in a real self-assembled quantum dot.

The $\langle charging energy" (N)$ is the energy needed to add a carrier to the dot that is already charged by N 1 carriers, (N) = E(N) = E(N)1), where E (N) is the correlated m any-body total energy of the ground state of the N -particle dot. The \addition energy" (N 1;N) (analogous to the di erence between ionization potential and electron a nity) indicates how much more energy is needed to add the N th carrier compared to the energy needed to add the N 1th carrier: (N 1;N) =1) = E(N) 2E(N 1) + E(N)(N) **(**N 2). In the Hartree Fock approximation, where the e ect of correlations is neglected but the direct C oulom b and exchange interactions are retained, simple expressions can be derived for the addition energies. To do so, one needs to decide rst what is the order of lling the single-particle s,pd, levels. A ssum ing the lling sequence of the left (L) hand side of Fig. 1a, obeying Hund's rule and the Aufbau principle, the addition energies are given by:

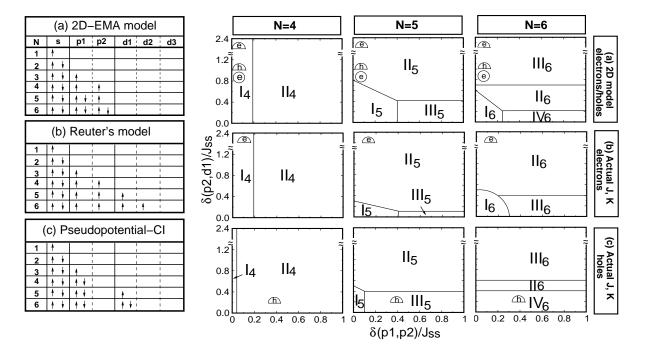


FIG.1: (Leff) The ground state con gurations (a) calculated from 2D parabolic model, (b) suggested by Reuter et al [15], and (c) calculated from pseudopotential-CIm ethod. (Right) The phase diagram s for N = 4, 5, 6 electrons/holes (a) calculated from 2D parabolic model, (b) for electrons using realistic C oulom b and exchange integrals, and (c) for holes using realistic C oulom b and exchange integrals. For N = 6, $d_{1}, d_{2} = d_{1}, d_{2}$ is assumed. The circles represent electrostatic dots, while lens represent self-assembled dots. The labels \e" and \h" inside the symbols denote electron and hole respectively. The con gurations of phases I, II, III, and IV are given in the text.

where $J_{i;j}$ and $K_{i;j}$ are, respectively, the Coulomb and exchange integrals between states i and j.

To calculate these addition energies, one must rst construct a single-particle Schrodinger equation model. In this step, one m ight need to account not only for quantum con nem ent, but also for electronic structure e ects such as multi-band (light-hole, heavy-hole, conduction) coupling; inter-valley (-X-L) coupling; spin-orbit coupling; and the e ect of strain and chem ical interm ixing. It is then possible to compute all of the single-particle level spacings and integrals entering Eq. (1), thus predict the value of $_{\rm H\,F}$ (N 1;N). A lternatively, one can neglect explicitly electronic structure e ects other than quantum con nem ent, and use instead a particle-in-aparabolic-box model, widely used in this eld[16, 19]. In this 2D-EMA, the p levels are degenerate ($_{p_1} = _{p_2}$), as are the d levels ($_{d_1}$ = $_{d_2}$ = $_{d_3}$) and the splitting between the s and p levels (" $_{\rm s}$ " $_{\rm p}$) and the splitting "d) between the p and d levels are both equal to ("p the harm onic oscillator frequency !. Furtherm ore, the assum ed parabolicity assures that analytic form ulas can be derived [19] for the Coulom b and exchange m atrix elements that relate all integrals needed for the addition energies to the value of a single J_{ss} , for instance in Eq. (1), $2J_{sp}$ J_{ss} $K_{sp} = J_{ss}=4$. Thus, universal results can be derived for electrons and holes as shown in the right (R) hand side of Fig. 1a, for N = 4, 5, 6. Since the

restriction of the 2D-EMA model to degenerate shells ($p_1 = p_2$, $d_1 = d_2 = d_3$) and to equidistant shells $(p_{p} = s_{d} = p)$ m ight be rather stringent [20], we allow in Fig. 1a (R), $p_1, p_2 = p_2$ p_1 and $p_2, d_1 = d_1$ p_2 to vary, calculating for each fN ; p_1, p_2 ; p_2, d_1 g the con guration which m in im izes the total-energy. This gives a phase diagram as a function of the parameters p_1, p_2 and p_2, d_1 in the unit of $J_{\rm ss}$ as shown in Fig. 1a (R) for particle num – ber N = 4, 5, 6. The 2D-EMA model yields for N = 4 two electronic phases: high-spin $I_4 = (s^{"}s^{\#})(p_1^{"})(p_2^{"})$ and low spin $\Pi_4 = (s^* s^{\#}) (p_1^* p_1^{\#})$. For N = 5, we nd three phases $I_5 = (s^{"}s^{\#})(p_1^{"})(p_2^{"})(d_1^{"}), II_5 = (s^{"}s^{\#})(p_1^{"}p_1^{\#})(p_2^{"}) and III_5 =$ $(s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(d_{1}^{"})$. For N = 6, we nd four phases, I_{6} = $(s^{"}s^{\#})(p_{1}^{"})(p_{2}^{"})(d_{1}^{"})(d_{2}^{"}), \Pi_{6} = (s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(p_{2}^{"})(d_{1}^{"}), \Pi_{6} =$ $(s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(p_{2}^{"}p_{2}^{\#})$ and $W_{6}=(s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(d_{1}^{"}d_{1}^{\#})$. To decide which of these phases is a ground state, we need to know in Fig. 1a (R) the value of $p_{1,p2}=J_{ss}$ and $p_{2,d1}=J_{ss}$. For electrons in self-assembled dots, the single-particle energy spacing is usually more than twice the Coulomb energy, so, $p_{2;d1} > 2J_{ss}$ [1, 19]. For holes, $p_{2;d1} =$ $1:17J_{ss}$ was determ ined from recent experiments[14, 15] and plyp2 = 0 is assumed in 2D-EMA model. This places in Fig. 1a (R) for both electrons and holes, phases I_4 , II_5 , III_6 as ground states for N = 4, 5, 6, respectively. The ground state con gurations of the 2D-EMA model are collected in Fig. 1a(L), for N = 1 - 6.

For electrons, the ground states of 2D-EMA model

TABLE I: Hole addition energies of self-assembled InAs/GaAs quantum dots in meV. The experimental values are from Ref. [15] at zero magnetic eld. The \G round State" values correspond to the low -spin con gurations as given in Fig. 1a(L) and the \Excited State" values to the high-spin con gurations assumed in Ref. 15 and given in Fig. 1b(L). The results of P seudopotential+CI" calculations correspond to the con gurations from Fig. 1c(L).

Addition	ddition Exp. 2D-EMA model		P seudopotential + C I						
Energy		G round state Excited state		2R = 20 nm		2R = 25 nm		2R = 27.5 nm	
		Fig.la(L)	Fig.1b(L)	h=2.5 nm	h=3.5 nm	h=2.5 nm	h= 3.5 nm	h=2.5 nm	h= 3.5 nm
_h (1;2)	23.9	F itted	F itted	24.1	19.0	21.9	17.5	21.0	16.7
h (2;3)	34.2	F itted	F itted	28.7	21.7	27.2	21,2	26.4	20.6
_h (3;4)	17.1	12	12	18.1	16.9	16.4	15.2	15.6	14.5
_h (4;5)	23.2	21	29	26.4	21.6	25.4	20.8	23.8	20.5
_h (5;6)	15.0	12	18	17.1	16.1	15.3	14.4	15.5	13.7

are corroborated by atom istic pseudopotential calculations [Fig.1b (R)], where we use the Coulom b integrals obtained from atom istic wavefunctions for electrons in a lens shape InA s/G aAs dot with 25 nm base and 2.5 nm height. This shape is realistic, according to experimental ndings [21], and predicts a fundamental photolum inescence line very close to the one observed in the charging experiment [15] at around 1 eV. O verall, the comparison between Figs. 2a and Figs. 2b shows that while the phase boundaries can change signi cantly when realistic wavefunctions are assumed instead of 2D -EMA values, the ground state symmetries for N = 5 and 6 electrons in self-assem bled dots remain unchanged and are far from other competing phases.

The foregoing analysis of loading of electrons [4, 5, 6]has been simplied by the fact that the single-band effective m ass m odel is not a drastic approximation given that in direct-gap zinc-blende m aterials electrons derive from a nondegenerate, spin-orbit-free 1c band which is energetically isolated from other states. The analysis of loading of holes, however, does not bene t from the same simplication, as holes derive from a mix of heavy-and light-hole states, invalidating [22] the classication of hole states as pure s or p or d levels and as pure heavy-hole or light-hole states [23]. Furtherm ore, as shown in Fig. 1a(R), unlike electrons, the ground states of holes are close to competing phases in the 2D -EM A phase diagram s, which require a more careful treatment. Nevertheless, the 2D-EMA model is still attractive in its simplicity and Reuter et al. [15] used it to analyze their hole charging results. The value of J_{ss} is directly accessible from experiments since it is well approximated by (1;2). The only remaining parameter in the 2D-EMA model is the single-particle energy splitd)= ! which can be extracted from ting (_s g) =(g measuring (2;3) = $(p_s) + J_{ss}=4$. Reuter et al [15] thus determ ined J_{ss} = 23.9 m eV and "_p "_s = 28 m eV. Since experimentally ve addition energies are available and only two were used in the tabove, the problem is overdeterm ined and it is possible to assess how well the

m odel reproduces the rem aining three experim ental data points. A ssum ing $p_{1,p_2} = 0$ and $p_{2,d_1} = d = p = s = 28$ m eV , yields the above m entioned $\rm_{p2;d1}{=}\,1.17\,J_{ss}$, leading to the phase diagram of Fig. 1a (R), with ground state phases: I_4 , II_5 and III_6 . If one calculates the addition energies of Eq.(1), using these ground-state con gurations one gets the values indicated by \2D -EM A m odel ground state" in Table I. However, this hole addition sequence contradicts the magnetic eld data of Ref. 15, which show that the hole d-levels are occupied before p-levels are lled completely (non-Aufbau) [15]. To explain their magnetic eld data, Reuter et al. [15] assum ed a hole 11ing sequence [Fig. 1b(L)] that relies on an ad hoc excited hole state instead of the the ground states predicted by the 2D-EMA model [Fig. 1a(L)]. In Table I, we compare the ensuing addition energies of both the ground state and excited state con gurations with experiments. We nd that the addition energies given by both scenarios of Fig. 1a(L) and 1b(L) show signi cant discrepancies from the experim ental values, with about 25-50 % error.

For holes, the discrepancy between the harm onic oscillator results Fig. 1a(L) (Aufbau con guration) and the magnetic eld data of Fig. 1b(L) (non-Aufbau conguration) is di cult to reconcile within the 2D-EMA model, since even relative large variations of the singleparticle energy parameters plyp2 and p2;d1 do not lead to a ground-state con guration change from Fig.1a(L) to Fig.1b(L). Our atom istic pseudopotential, plus CI calculations show di erent ground-state con gurations for holes than the above two models. As shown in Fig.1c(R), for N = 4, and N = 5, using an atom istic description the topology of the phase-diagram s are the same as in the 2D-EMA model, but the boundaries are shifted. As a result, for N = 4, the hole ground state is now phase $\Pi_4 = (s^*s^{\#}) (p_1^*p_1^{\#})$, not $I_4 = (s^*s^{\#}) (p_1^{\#}) (p_2^{\#})$, and for N = 5, the ground state is phase $\mathrm{III}_5\text{=}$ $(s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(d_{1}^{"}), \text{ not } \Pi_{5} = (s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(p_{2}^{"}). \text{ For } N = 6,$ the topology of the phase digram changed com pletely: phase $I_6 = (s^{"}s^{\#})(p_1^{"})(p_2^{"})(d_1^{"})(d_2^{"})$ disappeared, and the ground state is now IV₆ = $(s^{"}s^{\#})(p_{1}^{"}p_{1}^{\#})(d_{1}^{"}d_{1}^{\#})$. The

TABLE II:F inst hole C oulom b energy $J_{\rm ss}$ and single-particle energy level spacings in meV, from atom istic pseudopotential calculations for six di erent self-assembled len-shaped InA s/G aA s quantum dots.

	2R = 20 nm		2R =	25 nm	2R = 27.5 nm		
	h= 2.5	h=3.5	h=2.5	h= 3.5	h=2.5	h= 3.5	
J_{ss}	27.2	22.1	25.1	20.4	24,2	19.6	
p1;p2	10.9	11.3	7.1	9.5	5.8	7.9	
p2 ; d1	4.5	3.4	8.34	2.4	9.4	3.9	

ground-state con gurations are listed in Fig.1c(L) for N = 1 - 6. Using these new ground states, Table I com pares the experim ental addition energies and the calculated results for six di erent InA s/G aA s lens shaped quantum dots of di erent bases and heights. Very good agreem ent is obtained for the InAs dot with 20 nm base and 2.5 nm height, with di erences in the addition energies of less than 16%, compared with alm ost 50% error in 2D-EMA model (despite the fact that two of the addition energies were tted). The parameters p_{1,p_2} and $_{p2;d1}$ calculated for di erent dots are given in Table II and as shown in Fig. 1c(R), lie close to the center of the predicted phases II_4 , III_5 and IV_6 . This indicates the stability of our num erical results against possible variations of p1;p2 and p2;d1 due to shape an isotropy or alloy e ects. The addition energies we calculate from con guration interaction are di erent by about 1-3 m eV from those we calculate in Hartree-Fock, although they give the sam e ground state.

Ourpredicted charging pattern Fig. 1c(L)] shows that the level lling by holes does not follow the Aufbau principle nor the Hund's rules: d levels get led before the second p level, despite the fact that the d level is energetically more than 3 meV above the second p level. The non-trivial hole lling pattern is due to two reasons. F irst, the large p-level splitting leads to the p_2 level being energetically close to the d_1 level, i.e., $p_{2;d_1}$ is small. In Table II, we list the hole single-particle energy spacings and the rst hole C oulom b integrals J_{ss} for di erent dots. We see that p_1, p_2 (0.3 - 0.5) J_s and p₂;d₁ (0.2 -0.3) J_s, which dier signicantly from the assumption of 2D-EMA where, p1;p2 0, and p2;d1 Jss. Second, the C oulom b repulsion between the p_1 and the d level is lower than that between the two p levels, therefore the C oulom b energy can overcom e the single-particle energy spacing p2;d1, leading to the non-Aufbau charging pattem.

An important feature of the present theory is not only its compatibility with the zero eld experimental results but also with the magnetic eld dependence obtained in Ref. 15. The experimental results from Ref. 15 show that the spin Zeem an elect is signilicantly smaller than the orbital Zeem an and in the interpretation of the experimental results only the latter has to be taken into account. W ithin this approximation our theoretical results reproduce the experimental data for N = 1 - 6 holes given in Fig. 2 of Ref. 15, since our results have the same total orbital angular m om enta. The di erence in the total spin for con gurations assumed in Ref. 15 and in the present work is signi cant. W e suggest to identify the spin con gurations by measuring optically the nestructure of the N h + e ! (N) 1) h transition in large magnetic eld. W hile our suggested con gurations for the N = 4, 6 holes have closed-shell llings and only one single line with no ne-structure should be observed, the high-spin con guration suggested by Reuter et al. [15] should show a rich ne-structure that should become apparent, especially at high magnetic elds.

In conclusion, we analyzed the many-particle con gurations for electrons and holes in quantum dots in the form of phase diagram s. From these diagram s, we predict that the hole charging sequence presents surprising con gurations (not expected from e ective mass calculations) that violates the Aufbau principle as well as the H und's rule. Our results are in good agreem ent with recent experimental ndings and provide a novel way to study the charging of carriers in quantum dots.

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This is known from multi-excitons measurements [3] as well as from our theoretical analysis [24], showing that the underlying zinc-blende symmetry induces such splitting $p_1 \notin p_2$ and $d_1 \notin d_2$, even for cylindrically symmetric dots.

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